

BLF888B; BLF888BS

UHF power LDMOS transistor

Rev. 3 — 1 September 2015

AMPLEON

Product data sheet

1. Product profile

1.1 General description

A 650 W LDMOS RF power transistor for broadcast transmitter applications and industrial applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. Application information

RF performance at $V_{DS} = 50$ V unless otherwise specified.

Mode of operation	f (MHz)	$P_{L(AV)}$ (W)	$P_{L(M)}$ (W)	G_p (dB)	η_D (%)	IMD3 (dBc)	IMD _{shldr} (dBc)	PAR (dB)
RF performance in a common source 860 MHz narrowband test circuit								
2-tone, class-AB	$f_1 = 860$; $f_2 = 860.1$	250	-	21	46	-34	-	-
DVB-T (8k OFDM)	858	120	-	21	33	-	-31 [1]	8.2 [2]
RF performance in a common source 470 MHz to 860 MHz broadband test circuit								
DVB-T (8k OFDM)	858	120	-	20	32	-	-32 [1]	8.0 [2]

[1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

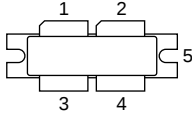
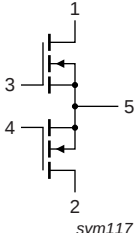
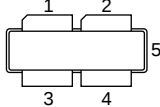
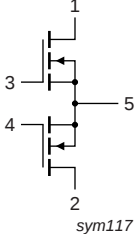
- Excellent ruggedness
- Optimum thermal behavior and reliability, $R_{th(j-c)} = 0.15$ K/W
- High power gain
- High efficiency
- Designed for broadband operation (470 MHz to 860 MHz)
- Internal input matching for high gain and optimum broadband operation
- Excellent reliability
- Easy power control
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

1.3 Applications

- Communication transmitter applications in the UHF band
- Industrial applications in the UHF band

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF888B (SOT539A)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		
BLF888BS (SOT539B)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF888B	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A
BLF888BS	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	104	V
V_{GS}	gate-source voltage		-0.5	+11	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C}$; $P_{L(AV)} = 125\text{ W}$	[1] 0.15	K/W

[1] $R_{th(j-c)}$ is measured under RF conditions.

6. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ °C}$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}$; $I_D = 2.4\text{ mA}$	[1] 104	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}$; $I_D = 240\text{ mA}$	[1] 1.4	1.9	2.4	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}$; $V_{DS} = 50\text{ V}$	-	-	2.8	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$; $V_{DS} = 10\text{ V}$	-	38	-	A
I_{GSS}	gate leakage current	$V_{GS} = 10\text{ V}$; $V_{DS} = 0\text{ V}$	-	-	280	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$; $I_D = 8.5\text{ A}$	[1] -	120	-	$\text{m}\Omega$
C_{iss}	input capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 50\text{ V}$; $f = 1\text{ MHz}$	[2] -	210	-	pF
C_{oss}	output capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 50\text{ V}$; $f = 1\text{ MHz}$	-	67	-	pF
C_{rss}	reverse transfer capacitance	$V_{GS} = 0\text{ V}$; $V_{DS} = 50\text{ V}$; $f = 1\text{ MHz}$	-	1.35	-	pF

[1] I_D is the drain current.

[2] Capacitance values without internal matching.

Table 7. RF characteristics

RF characteristics in Ampleon production narrowband test circuit; $T_{case} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
2-Tone, class-AB						
V_{DS}	drain-source voltage		-	50	-	V
I_{Dq}	quiescent drain current		[1] -	1.3	-	A
$P_{L(AV)}$	average output power	$f_1 = 860\text{ MHz}$; $f_2 = 860.1\text{ MHz}$	250	-	-	W
G_p	power gain	$f_1 = 860\text{ MHz}$; $f_2 = 860.1\text{ MHz}$	20	21	-	dB
η_D	drain efficiency	$f_1 = 860\text{ MHz}$; $f_2 = 860.1\text{ MHz}$	42	46	-	%
IMD3	third-order intermodulation distortion	$f_1 = 860\text{ MHz}$; $f_2 = 860.1\text{ MHz}$	-	-34	-30	dBc

Table 7. RF characteristics ...continued

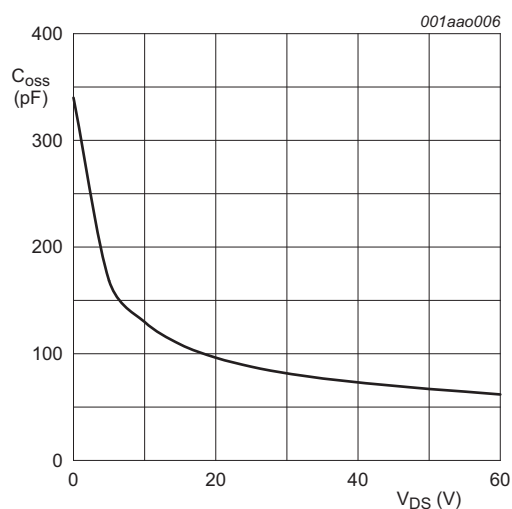
RF characteristics in Ampleon production narrowband test circuit; $T_{case} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
DVB-T (8k OFDM), class-AB						
V_{DS}	drain-source voltage		-	50	-	V
I_{Dq}	quiescent drain current		[1]	1.3	-	A
$P_{L(AV)}$	average output power	$f = 858\text{ MHz}$	120	-	-	W
G_p	power gain	$f = 858\text{ MHz}$	20	21	-	dB
η_D	drain efficiency	$f = 858\text{ MHz}$	30	33	-	%
IMD_{shldr}	intermodulation distortion shoulder	$f = 858\text{ MHz}$	[2]	-31	-27	dBc
PAR	peak-to-average ratio	$f = 858\text{ MHz}$	[3]	8.2	-	dB

[1] I_{dq} for total device

[2] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[3] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.



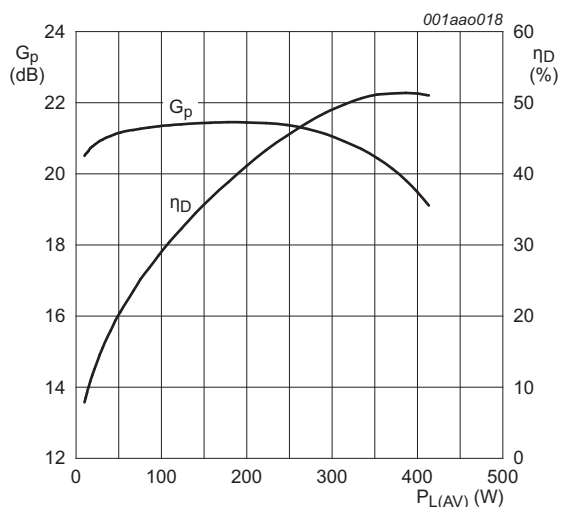
$V_{GS} = 0\text{ V}$; $f = 1\text{ MHz}$.

Fig 1. Output capacitance as a function of drain-source voltage; typical values per section

7. Application information

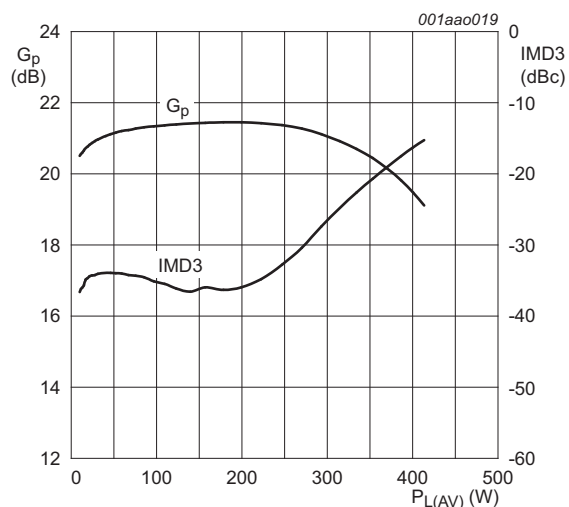
7.1 Narrowband RF figures

7.1.1 2-Tone



$V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source narrowband 860 MHz test circuit.

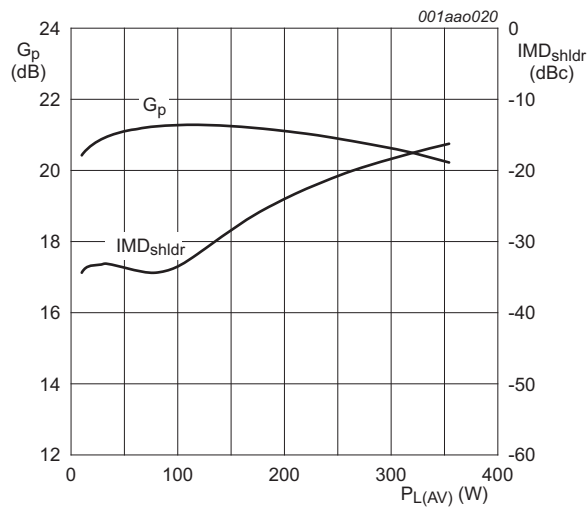
Fig 2. 2-Tone power gain and drain efficiency as function of load power; typical values



$V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source narrowband 860 MHz test circuit.

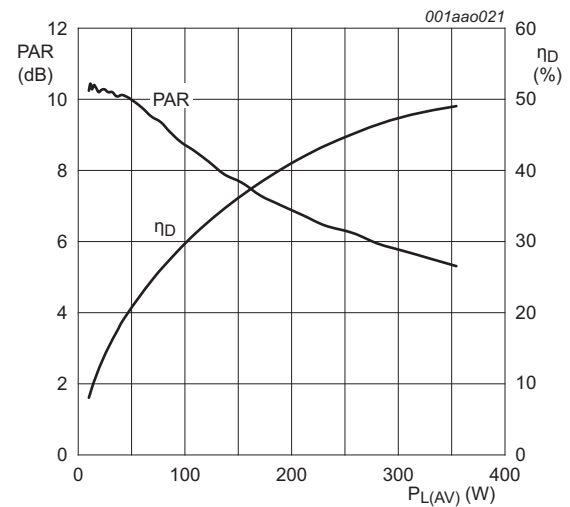
Fig 3. 2-Tone power gain and third order intermodulation distortion as load power; typical values

7.1.2 DVB-T



$V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source narrowband 860 MHz test circuit.

Fig 4. DVB-T power gain and intermodulation distortion shoulder as function of load power; typical values

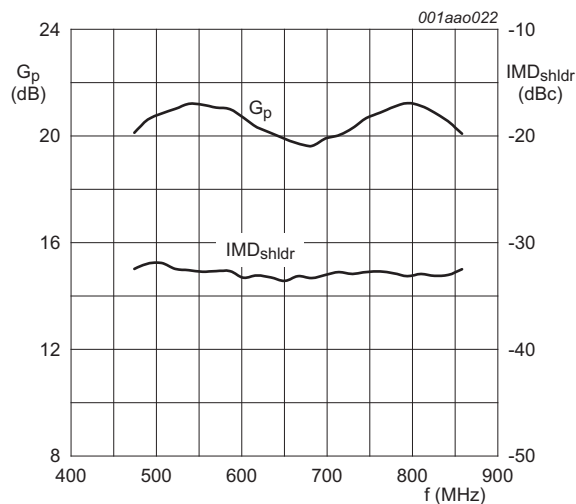


$V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source narrowband 860 MHz test circuit.

Fig 5. DVB-T peak-to-average ratio and drain efficiency as function of load power; typical values

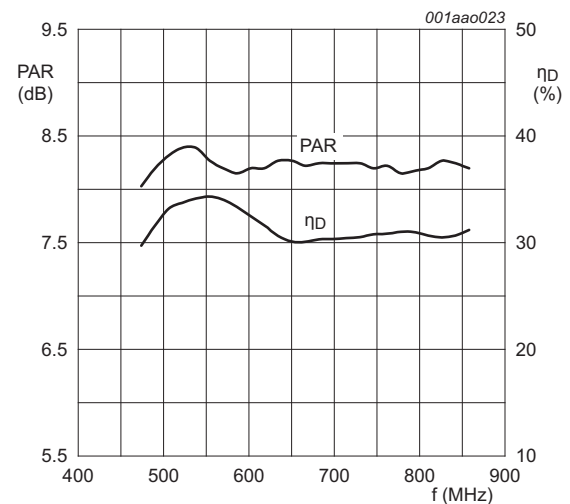
7.2 Broadband RF figures

7.2.1 DVB-T



$P_{L(AV)} = 120$ W; $V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source broadband test circuit as described in [Section 8](#).

Fig 6. DVB-T power gain and intermodulation distortion shoulder as function of frequency; typical values



$P_{L(AV)} = 120$ W; $V_{DS} = 50$ V; $I_{DQ} = 1.3$ A; measured in a common source broadband test circuit as described in [Section 8](#).

Fig 7. DVB-T peak-to-average ratio and drain efficiency as function of frequency; typical values

7.3 Impedance information

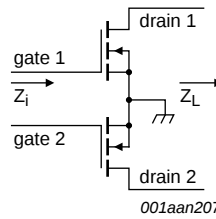


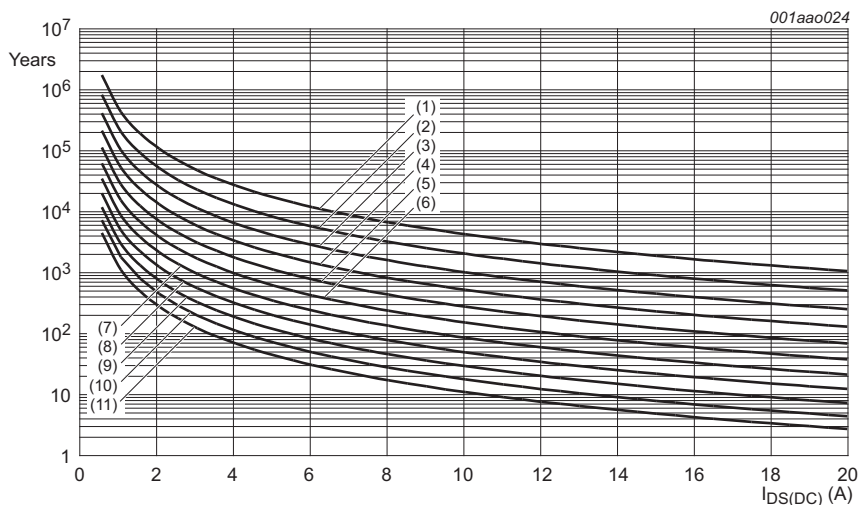
Fig 8. Definition of transistor impedance

Table 8. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 50 \text{ V}$ and $P_{L(AV)} = 120 \text{ W}$ (DVB-T).

f MHz	Z_i Ω	Z_L Ω
300	$0.617 - j1.715$	$4.792 + j0.947$
325	$0.635 - j1.355$	$4.707 + j0.994$
350	$0.655 - j1.026$	$4.619 + j1.035$
375	$0.677 - j0.721$	$4.528 + j1.069$
400	$0.702 - j0.435$	$4.435 + j1.097$
425	$0.731 - j0.164$	$4.340 + j1.118$
450	$0.762 + j0.096$	$4.243 + j1.134$
475	$0.798 + j0.347$	$4.147 + j1.143$
500	$0.839 + j0.592$	$4.049 + j1.146$
525	$0.884 + j0.833$	$3.952 + j1.144$
550	$0.936 + j1.072$	$3.855 + j1.136$
575	$0.995 + j1.310$	$3.759 + j1.123$
600	$1.063 + j1.549$	$3.663 + j1.105$
625	$1.141 + j1.791$	$3.569 + j1.083$
650	$1.230 + j2.037$	$3.477 + j1.055$
675	$1.334 + j2.289$	$3.385 + j1.024$
700	$1.456 + j2.548$	$3.296 + j0.989$
725	$1.599 + j2.814$	$3.209 + j0.949$
750	$1.768 + j3.090$	$3.123 + j0.907$
775	$1.971 + j3.376$	$3.039 + j0.861$
800	$2.214 + j3.671$	$2.958 + j0.812$
825	$2.510 + j3.975$	$2.879 + j0.761$
850	$2.873 + j4.282$	$2.801 + j0.706$
875	$3.320 + j4.584$	$2.726 + j0.650$
900	$3.875 + j4.865$	$2.654 + j0.591$
925	$4.562 + j5.095$	$2.583 + j0.530$
950	$5.409 + j5.223$	$2.514 + j0.467$
975	$6.426 + j5.166$	$2.448 + j0.403$
1000	$7.587 + j4.807$	$2.384 + j0.337$

7.4 Reliability



TTF (0.1 % failure fraction).

The reliability at pulsed conditions can be calculated as follows: $TTF (0.1 \%) \times 1 / \delta$.

- (1) $T_j = 100 \text{ }^{\circ}\text{C}$
- (2) $T_j = 110 \text{ }^{\circ}\text{C}$
- (3) $T_j = 120 \text{ }^{\circ}\text{C}$
- (4) $T_j = 130 \text{ }^{\circ}\text{C}$
- (5) $T_j = 140 \text{ }^{\circ}\text{C}$
- (6) $T_j = 150 \text{ }^{\circ}\text{C}$
- (7) $T_j = 160 \text{ }^{\circ}\text{C}$
- (8) $T_j = 170 \text{ }^{\circ}\text{C}$
- (9) $T_j = 180 \text{ }^{\circ}\text{C}$
- (10) $T_j = 190 \text{ }^{\circ}\text{C}$
- (11) $T_j = 200 \text{ }^{\circ}\text{C}$

Fig 9. BLF888B; BLF888BS electromigration ($I_{DS(DC)}$, total device)

8. Test information

Table 9. List of components

For test circuit, see [Figure 10](#), [Figure 11](#) and [Figure 12](#).

Component	Description	Value	Remarks
B1, B2	semi rigid coax	25 Ω ; 49.5 mm	UT-090C-25 (EZ 90-25)
C1	multilayer ceramic chip capacitor	12 pF	[1]
C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	8.2 pF	[1]
C7	multilayer ceramic chip capacitor	6.8 pF	[2]
C8	multilayer ceramic chip capacitor	2.7 pF	[2]
C9	multilayer ceramic chip capacitor	2.2 pF	[2]
C10, C13, C14	multilayer ceramic chip capacitor	100 pF	[3]
C11, C12	multilayer ceramic chip capacitor	10 pF	[2]
C15, C16	multilayer ceramic chip capacitor	4.7 μ F, 50 V	Kemet C1210X475K5RAC-TU or capacitor of same quality.
C17, C18, C23, C24	multilayer ceramic chip capacitor	100 pF	[2]
C19, C20	multilayer ceramic chip capacitor	10 μ F, 50 V	TDK C570X7R1H106KT000N or capacitor of same quality.
C21, C22	electrolytic capacitor	470 μ F; 63 V	
C30	multilayer ceramic chip capacitor	10 pF	[4]
C31	multilayer ceramic chip capacitor	9.1 pF	[4]
C32	multilayer ceramic chip capacitor	3.9 pF	[4]
C33, C34, C35	multilayer ceramic chip capacitor	100 pF	[4]
C36, C37	multilayer ceramic chip capacitor	4.7 μ F, 50 V	TDK C4532X7R1E475MT020U or capacitor of same quality.
L1	microstrip	-	[5] (W $\times$ L) 15 mm $\times$ 13 mm
L2	microstrip	-	[5] (W $\times$ L) 5 mm $\times$ 26 mm
L3, L32	microstrip	-	[5] (W $\times$ L) 2 mm $\times$ 49.5 mm
L4	microstrip	-	[5] (W $\times$ L) 1.7 mm $\times$ 3.5 mm
L5	microstrip	-	[5] (W $\times$ L) 2 mm $\times$ 9.5 mm
L30	microstrip	-	[5] (W $\times$ L) 5 mm $\times$ 13 mm
L31	microstrip	-	[5] (W $\times$ L) 2 mm $\times$ 11 mm
L33	microstrip	-	[5] (W $\times$ L) 2 mm $\times$ 3 mm
R1, R2	wire resistor	10 Ω	
R3, R4	SMD resistor	5.6 Ω	0805
R5, R6	wire resistor	100 Ω	
R7, R8	potentiometer	10 k Ω	

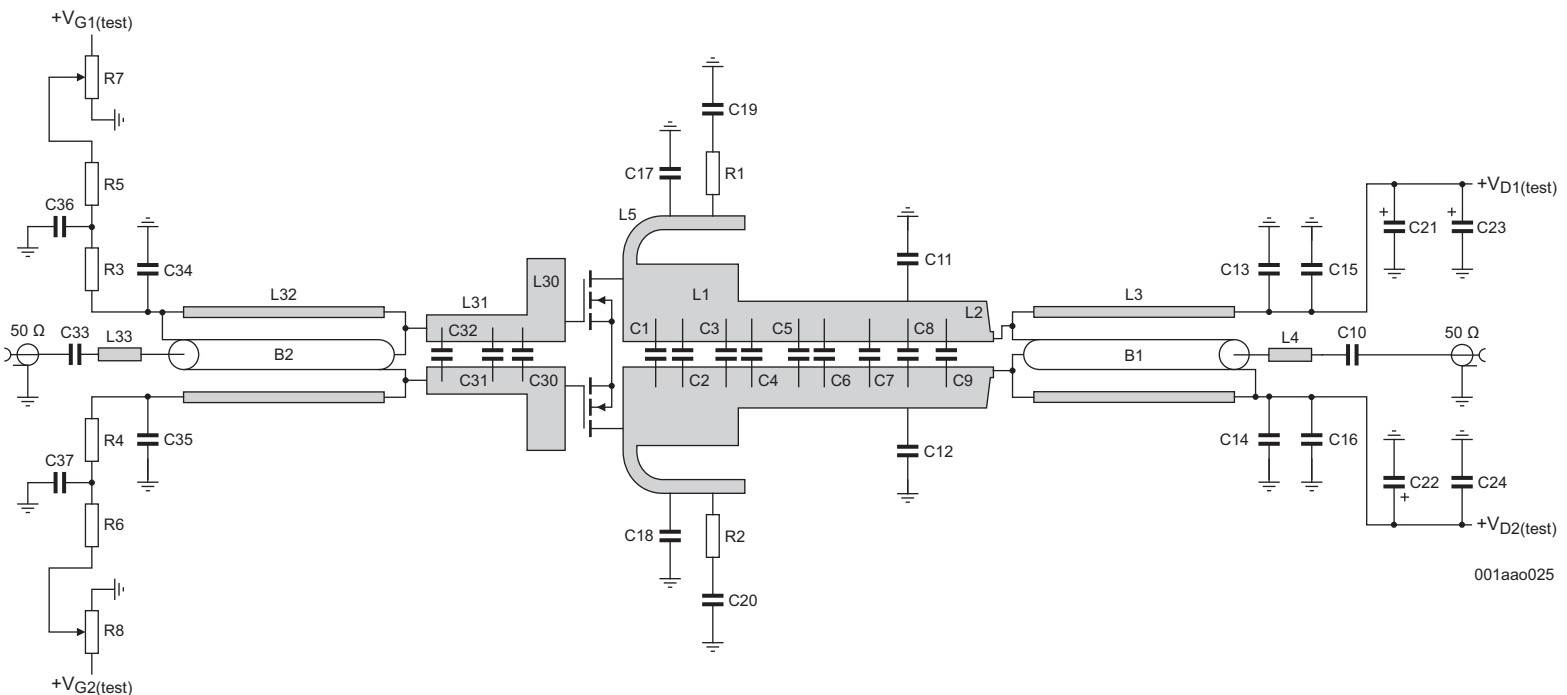
[1] American technical ceramics type 800R or capacitor of same quality.

[2] American technical ceramics type 800B or capacitor of same quality.

[3] American technical ceramics type 180R or capacitor of same quality.

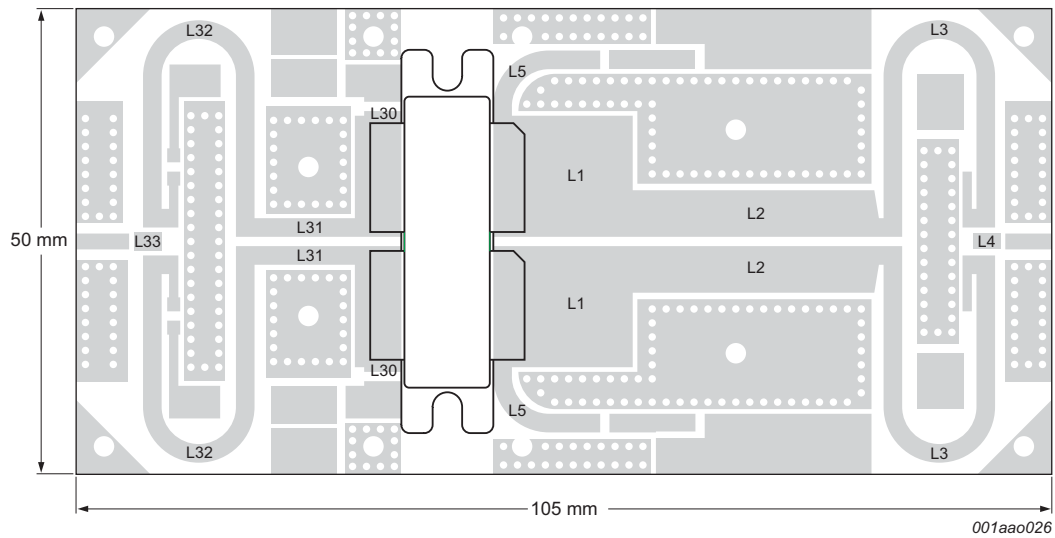
[4] American technical ceramics type 100A or capacitor of same quality.

[5] Printed-Circuit Board (PCB): Taconic RF35; $\epsilon_r = 3.5$ F/m; height = 0.762 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.



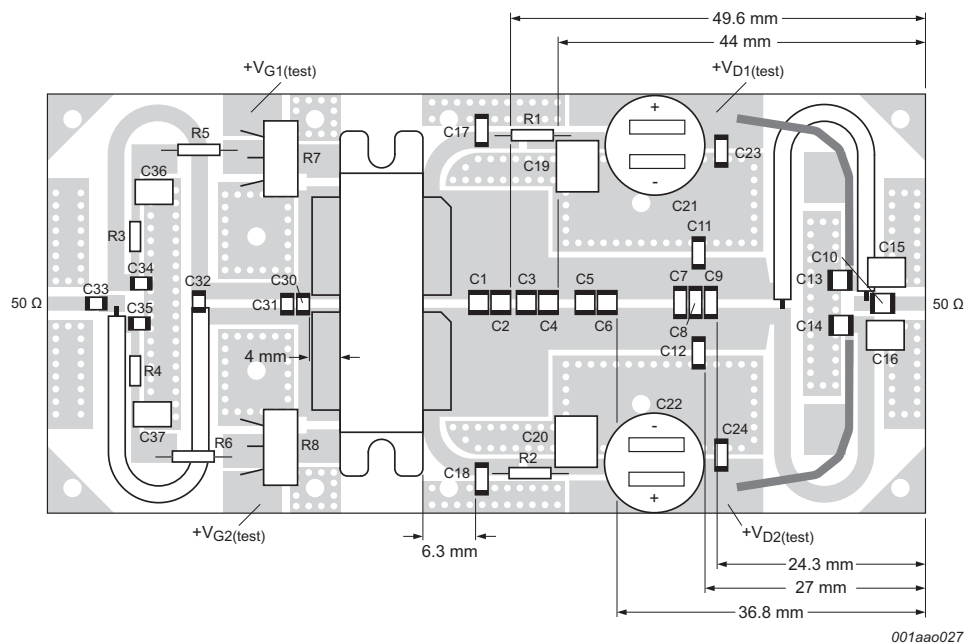
See [Table 9](#) for a list of components.

Fig 10. Class-AB common source broadband amplifier; $V_{D1(test)}$, $V_{D2(test)}$, $V_{G1(test)}$ and $V_{G2(test)}$ are drain and gate test voltages



See [Table 9](#) for a list of components.

Fig 11. Printed-Circuit Board (PCB) for class-AB common source amplifier



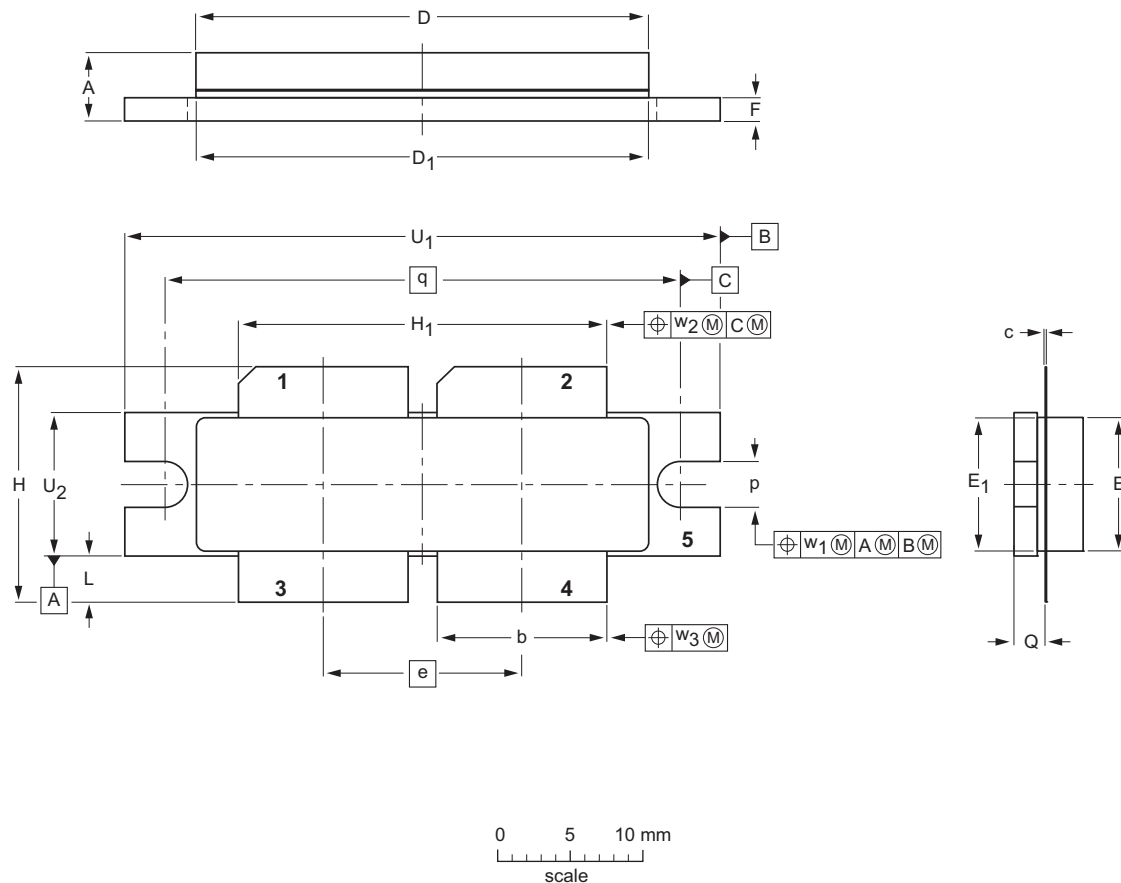
See [Table 9](#) for a list of components.

Fig 12. Component layout for class-AB common source amplifier

9. Package outline

Flanged balanced ceramic package; 2 mounting holes; 4 leads

SOT539A



DIMENSIONS (millimetre dimensions are derived from the original inch dimensions)

UNIT	A	b	c	D	D ₁	e	E	E ₁	F	H	H ₁	L	p	Q	q	U ₁	U ₂	w ₁	w ₂	w ₃
mm	4.7 4.2	11.81 11.56	0.18 0.10	31.55 30.94	31.52 30.96	13.72	9.50 9.30	9.53 9.27	1.75 1.50	17.12 16.10	25.53 25.27	3.48 2.97	3.30 3.05	2.26 2.01	35.56	41.28 41.02	10.29 10.03	0.25	0.51	0.25
inches	0.185 0.165	0.465 0.455	0.007 0.004	1.242 1.218	1.241 1.219	0.540	0.374 0.366	0.375 0.365	0.069 0.059	0.674 0.634	1.005 0.995	0.137 0.117	0.130 0.120	0.089 0.079	1.400	1.625 1.615	0.405 0.395	0.010	0.020	0.010

Note

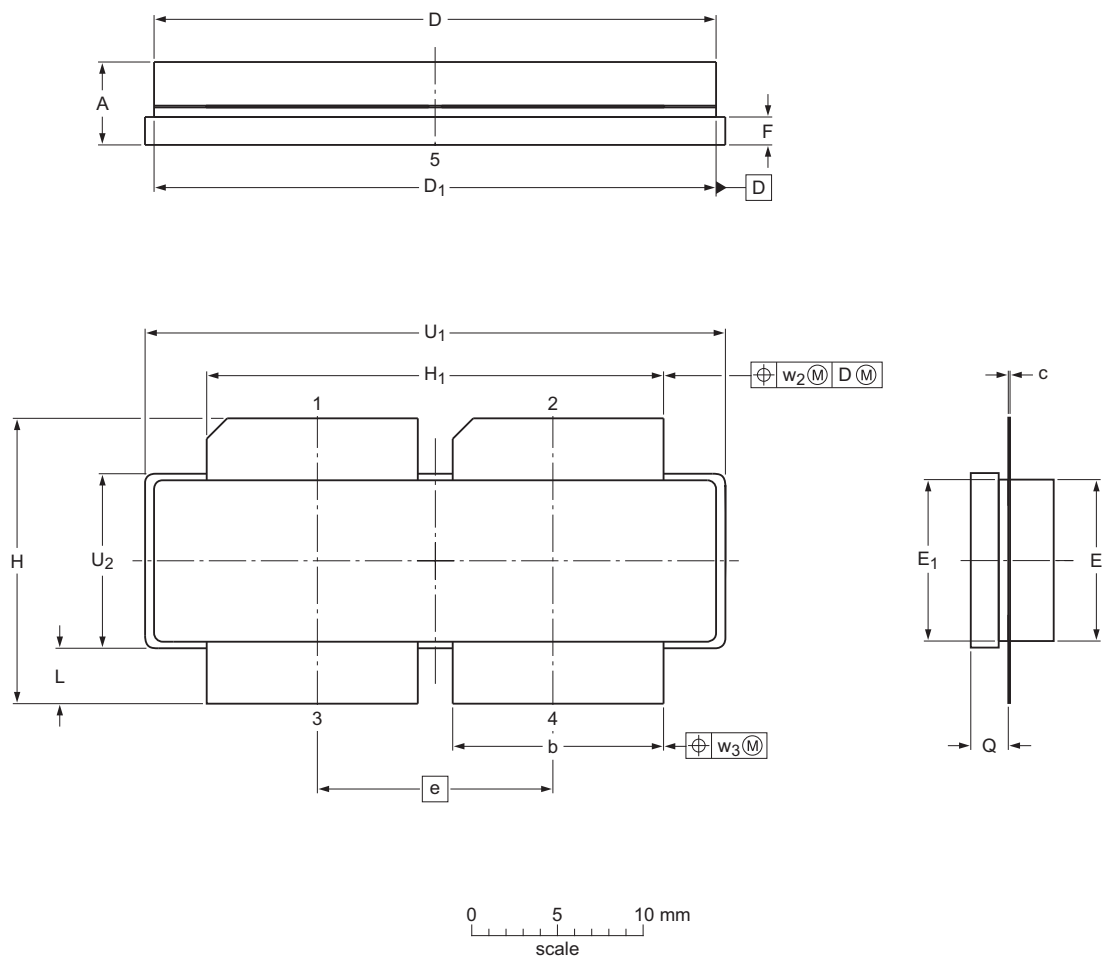
1. millimeter dimensions are derived from the original inch dimensions.
2. recommended screw pitch dimension of 1.52 inch (38.6 mm) based on M3 screw.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT539A						10-02-02 12-05-02

Fig 13. Package outline SOT539A

Earless flanged balanced ceramic package; 4 leads

SOT539B



Dimensions																	
Unit ⁽¹⁾	A	b	c	D	D ₁	E	E ₁	e	F	H	H ₁	L	Q	U ₁	U ₂	w ₂	w ₃
mm	max	4.7	11.81	0.18	31.55	31.52	9.5	9.53	1.75	17.12	25.53	3.48	2.26	32.39	10.29	0.25	0.25
	nom							13.72									
inches	max	0.185	0.465	0.007	1.242	1.241	0.374	0.375	0.069	0.674	1.005	0.137	0.089	1.275	0.405	0.01	0.01
	nom							0.54									
	min	0.165	0.455	0.004	1.218	1.219	0.366	0.365	0.059	0.634	0.995	0.117	0.079	1.265	0.395		

Note 1. millimeter dimensions are derived from the original inch dimensions. sot539b_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT539B						12-05-02 13-05-24

Fig 14. Package outline SOT539B

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

11. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
DVB	Digital Video Broadcast
DVB-T	Digital Video Broadcast - Terrestrial
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
TTF	Time-To-Failure
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF888B_BLF888BS#3	20150901	Product data sheet	-	BLF888B_BLF888BS v.2
Modifications:	- The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. - Legal texts have been adapted to the new company name where appropriate.			
BLF888B_BLF888BS v.2	20130712	Product data sheet	-	BLF888B_BLF888BS v.1
BLF888B_BLF888BS v.1	20111017	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an

Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.ampleon.com/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon's standard warranty and Ampleon's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

13.4 Licenses

ICs with DVB-T or DVB-T2 functionality

Use of this product in any manner that complies with the DVB-T or the DVB-T2 standard may require licenses under applicable patents of the DVB-T respectively the DVB-T2 patent portfolio, which license is available from Sisvel S.p.A., Via Sestriere 100, 10060 None (TO), Italy, and under applicable patents of other parties.

13.5 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

14. Contact information

For more information, please visit:
<http://www.ampleon.com>

For sales office addresses, please visit:
<http://www.ampleon.com/sales>

15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	3
6	Characteristics	3
7	Application information	5
7.1	Narrowband RF figures	5
7.1.1	2-Tone	5
7.1.2	DVB-T	6
7.2	Broadband RF figures	6
7.2.1	DVB-T	6
7.3	Impedance information	7
7.4	Reliability	8
8	Test information	9
9	Package outline	12
10	Handling information	14
11	Abbreviations	14
12	Revision history	14
13	Legal information	15
13.1	Data sheet status	15
13.2	Definitions	15
13.3	Disclaimers	15
13.4	Licenses	16
13.5	Trademarks	16
14	Contact information	16
15	Contents	17

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Ampleon The Netherlands B.V. 2015. All rights reserved.

For more information, please visit: <http://www.ampleon.com>
For sales office addresses, please visit: <http://www.ampleon.com/sales>

Date of release: 1 September 2015

Document identifier: BLF888B_BLF888BS#3